

Selective Pure-Phase Synthesis of the Multiferroic BaMF₄ (M = Mg, Mn, Co, Ni, and Zn) Family

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Abstract: A low temperature, high yield hydrothermal route has been discovered for the phase-pure synthesis of the multiferroic BaMF₄ (M = Mg, Mn, Co, Ni, and Zn) family. The synthesis involves the use of CF₃COOH instead of HF in an aqueous medium and, under the correct conditions, produces pure and polycrystalline BaMF₄. In addition to the synthetic description, second-harmonic generation, thermogravimetric, and differential scanning calorimetry data are presented.

Multiferroic materials, compounds where at least two primary ferroic — ferroelectric, ferromagnetic, ferroelastic, etc. — properties occur in the same materials, are of topical interest attributable to their applications in advanced devices.^{1–3} With such materials, the magnetic properties may be controlled by an electric field and vice versa. A great deal of effort is dedicated to not only discovering new multiferroic materials, e.g., MnWO₄^{4–6} and Ca₃CoMnO₆,^{7,8} but also investigating multiferroic behavior in known materials, e.g., BiFeO₃.^{9–16} A family of materials that has received renewed interest are the mixed-metal fluorides BaMF₄ (M = Mg, Mn, Fe, Co, Ni, and Zn).^{17–21} These iso-structural and crystallographically polar materials — all of the materials crystallize in the polar space group *Cmc*2₁ — are ferroelectric at room temperature for M = Mg, Co, Ni, and Zn²² and exhibit antiferromagnetic ordering with *T_N* ≈ 20–80 K for M = Mn, Fe, Co, and Ni.²³ Thus simultaneous ferroelectric and antiferromagnetic behavior, at low temperatures, may only be observed in BaCoF₄ and BaNiF₄.

Originally, the BaMF₄ family of materials were grown as crystals from the melt of BaF₂ and MF₂ in an HF atmosphere at elevated temperatures — above 800 °C.²⁴ Large, centimeter size, single crystals of BaMgF₄ have been grown by Czochralski and Bridgeman methods. In these reports either CF₄ or anhydrous HF gas was used at ~920 °C.^{25–27} Sol-gel methods to synthesize polycrystalline BaMgF₄ have also been reported; however, in these reports BaF₂ and/or MgF₂ impurities were found.^{28,29} To date, there are no published reports on the bulk, polycrystalline, *pure-phase* syntheses of the BaMF₄ family of materials. Such syntheses would aid in growing high quality films of these materials, as the pure bulk materials could be used as an ablation target. In this communication, we report on the synthesis of *pure and polycrystalline* BaMF₄ (M = Mg, Mn, Co, Ni, and Zn) through a convenient low temperature hydrothermal route.

All of the materials were synthesized by combining the reagents (see Table 1) into separate 23 mL autoclaves. The autoclaves were closed, heated to 230 °C, held for 24 h, and cooled slowly to room temperature at 6 °C h⁻¹. The mother liquor was decanted from the products, and the products were recovered by filtration and washed with distilled water. Reagent ratios used were as follows (see Supporting Information, S1, for complete details regarding the synthetic procedure).

Table 1. Reagent Amounts and Yields for the Synthesis of BaMF₄ (M = Mg, Mn, Co, Ni, and Zn)

	BaMgF ₄	BaMnF ₄	BaCoF ₄	BaNiF ₄	BaZnF ₄
BaF ₂	0.187 g	0.200 g	0.150 g	0.100 g	0.180 g
MF ₂	0.245 g ^a	0.106 g	0.110 g	0.385 g ^b	0.351 g ^b
CF ₃ COOH	4 mL	2 mL	3 mL	5 mL	4 mL
H ₂ O	5 mL	5 mL	5 mL	5 mL	5 mL
Yield ^c	70%	80%	70%	80%	80%

^a For BaMgF₄, Mg(ac)₂·4H₂O was used. ^b For BaNiF₄ and BaZnF₄, MF₂·4H₂O was used. ^c Yields based on BaF₂.

All of the reported materials, BaMF₄ (M = Mg, Mn, Co, Ni, and Zn), were synthesized as phase-pure polycrystalline powders. Experimental and calculated X-ray diffraction (XRD) data for BaNiF₄ are shown below (see Figure 1). Powder XRD data for the other reported phases have been deposited in the Supporting Information (see Figure S2).

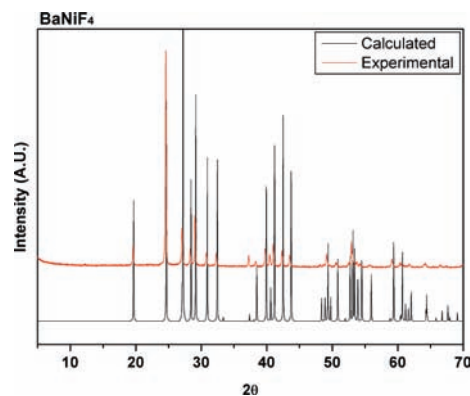


Figure 1. Calculated (black) and experimental (red) powder X-ray diffraction data for BaNiF₄.

Additionally, magnetic measurements were performed on BaNiF₄ to confirm the magnetic ordering. As seen in Figure S3, an antiferromagnetic transition at ~60 K is observed, consistent with previous reports.²³ With our hydrothermal method, we were also able to grow crystallographic quality crystals of BaMnF₄, BaCoF₄, and BiNiF₄. Crystallographic information for these three materials have been included in the Supporting Information. The structures are consistent with previous reports (see Table S4). Briefly, BaMF₄ (M = Mg, Mn, Co, Ni, and Zn) represent an iso-structural family of materials that contain layers of corner-shared MF₆ octahedra that are separated by Ba²⁺ cations (see Figure 2). The M–F bond distances, for BaMnF₄, BaCoF₄, and BiNiF₄, range from 1.981(9) to 2.159(5) Å, with Ba–F distances of 2.611(5)–3.355(5) Å. Bond valence calculations^{30,31} resulted in values ranging from 1.85 to 2.02 for the Ba²⁺ cation and 1.95, 1.99, and 2.00 for Mn²⁺, Co²⁺, and Ni²⁺, respectively. In connectivity terms, the structures may

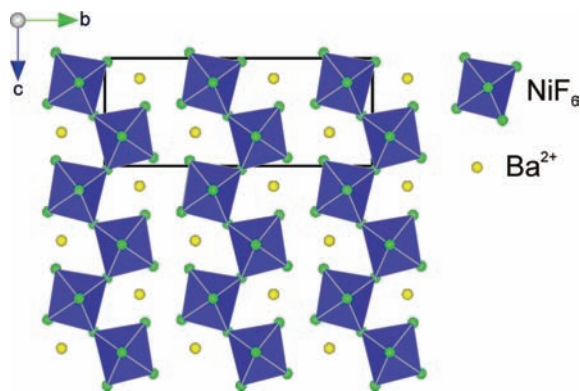


Figure 2. Polyhedral diagram of BaNiF₄ in the *bc*-plane.

be written as $[\text{MF}_{4/2}\text{F}_{2/1}]^{2-}$ with the charge balance retained by the Ba²⁺ cations.

Functional property characterization of the BaMF₄ family has been reported. These include ferroelectric,²² piezoelectric,²⁴ non-linear optical,³² magnetic,²³ and neutron diffraction measurements.¹⁹ More recently a first principles study on the origin of the ferroelectric behavior has been reported.²¹ We performed powder second-harmonic generating (SHG) measurements on the reported materials and determined that all of the materials as type 1 phase-matchable with an SHG efficiency of approximately $2 \times \alpha\text{-SiO}_2$ (see Figure S5). This relatively weak SHG efficiency is not too surprising as there are no polarizable cations — octahedrally coordinated d⁰ transition metals or lone-pair cations in the materials. Thermogravimetric measurements indicated that BaMF₄ is thermally stable up to 550 °C under N₂ (see Figure S6). Above this temperature, the materials decompose to BaF₂ and other mixed-metal fluorides (see Figure S7). BaMF₄ materials are stable above 750 °C in both gaseous HF and CF₄ atmospheres;^{25–27} however under N₂ the materials decompose above 550 °C. Differential scanning calorimetry measurements on all of the reported materials revealed no phase changes up to 500 °C (see Figure S8). Infrared data revealed $\nu_{\text{M-F}}$ stretches (M = Mg, Mn, Co, Ni or Zn) between 624 and 425 cm⁻¹ and $\nu_{\text{Ba-F}}$ vibrations between 427 and 409 cm⁻¹ (see Figure S9). These assignments are consistent with previous reports.³³

In summary, we have discovered a convenient hydrothermal route for the low temperature and high yield phase-pure synthesis of the multiferroic family BaMF₄ (M = Mg, Mn, Co, Ni or Zn). The method avoids the use of HF by using a milder fluorinating agent, CF₃COOH, in an aqueous medium. The reported method provides a mild route for the bulk synthesis of these multiferroic materials and, ultimately, may be used toward the development of targets for thin film growth. We are continuing our hydrothermal efforts using CF₃COOH toward the synthesis of other mixed-metal fluorides.

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Supporting Information Available: The complete synthetic procedure, powder X-ray diffraction, magnetic susceptibility, single crystal (cif), powder second-harmonic generation, thermogravimetric, differential scanning calorimetry, and infrared spectroscopy data are available. This material is available free of charge via the Internet at <http://pubs.acs.org>.

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